Designer's™ Data Sheet

Insulated Gate Bipolar Transistor with Anti-Parallel Diode N-Channel Enhancement-Mode Silicon Gate

This Insulated Gate Bipolar Transistor (IGBT) is co-packaged with a soft recovery ultra-fast rectifier and uses an advanced termination scheme to provide an enhanced and reliable high voltage blocking capability. Short circuit rated IGBT's are specifically suited for applications requiring a guaranteed short circuit withstand time such as Motor Control Drives. Fast switching characteristics result in efficient operation at high frequencies. Co-packaged IGBT's save space, reduce assembly time and cost.

- Industry Standard High Power TO-264 Package (TO-3PBL)
- High Speed E_{off}: 216 μJ/A typical at 125°C
- High Short Circuit Capability 10 μs minimum

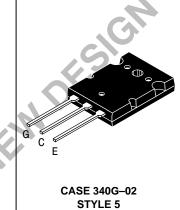
MAXIMUM RATINGS (T₁ = 25°C unless otherwise noted)

- Soft Recovery Free Wheeling Diode is included in the package
- Robust High Voltage Termination
- Robust RBSOA

MGY25N120D

Motorola Preferred Device

IGBT & DIODE IN TO-264 25 A @ 90°C 38 A @ 25°C 1200 VOLTS SHORT CIRCUIT RATED



TO-264

Rating	Symbol	Value	Unit	
Collector–Emitter Voltage	V _{CES}	1200	Vdc	
Collector–Gate Voltage ($R_{GE} = 1.0 M\Omega$)	V _{CGR}	1200	Vdc	
Gate-Emitter Voltage — Continuous	V _{GE}	±20	Vdc	
Collector Current—Continuous @ $T_C = 25^{\circ}C$ ——Continuous @ $T_C = 90^{\circ}C$ ——Repetitive Pulsed Current (1)	I _{C25} I _{C90} I _{CM}	38 25 76	Adc Apk	
Total Power Dissipation @ T _C = 25°C Derate above 25°C	PD	212 1.69	Watts W/°C	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to 150	°C	
Short Circuit Withstand Time (V_{CC} = 720 Vdc, V_{GE} = 15 Vdc, T_J = 125°C, R_G = 20 Ω)	t _{sc}	10	μs	
Thermal Resistance — Junction to Case – IGBT — Junction to Case – Diode — Junction to Ambient	R _{θJC} R _{θJC} R _{θJA}	0.6 0.9 35	°C/W	
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	TL	260	°C	
Mounting Torque, 6–32 or M3 screw	10 lbf•in (1.13 N•m)			

(1) Pulse width is limited by maximum junction temperature. Repetitive rating.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

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Preferred devices are Motorola recommended choices for future use and best overall value.





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ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Ch	aracteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector-to-Emitter Breakdown V	oltage	V _{(BR)CES}				Vdc
(V _{GE} = 0 Vdc, I _C = 25 μAdc) Temperature Coefficient (Positiv	e)		1200	 960	_	mV/°C
i v	,			000		μAdc
Zero Gate Voltage Collector Current ($V_{CE} = 1200 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}$)		ICES	_	_	100	μΑυσ
$(V_{CE} = 1200 \text{ Vdc}, V_{GE} = 0 \text{ Vdc}, T_{J} = 125^{\circ}\text{C})$			—	—	2500	
Gate-Body Leakage Current (V _{GE}	= \pm 20 Vdc, V _{CE} = 0 Vdc)	I _{GES}	_	—	250	nAdc
ON CHARACTERISTICS (1)						
Collector-to-Emitter On-State Vo	tage	V _{CE(on)}		0.07	0.04	Vdc
(V _{GE} = 15 Vdc, I _C = 12.5 Adc) (V _{GE} = 15 Vdc, I _C = 12.5 Adc, T	ı = 125°C)		_	2.37 2.15	3.24	
$(V_{GE} = 15 \text{ Vdc}, I_C = 12.5 \text{ Adc}, I_J = 125 \text{ C})$ $(V_{GE} = 15 \text{ Vdc}, I_C = 25 \text{ Adc})$			—	2.98	4.19	
Gate Threshold Voltage		V _{GE(th)}				Vdc
$(V_{CE} = V_{GE}, I_C = 1.0 \text{ mAdc})$ Threshold Temperature Coefficient	ent (Negative)		4.0	6.0 10	8.0	mV/°C
Forward Transconductance (V _{CE} =		0.		12		Mhos
YNAMIC CHARACTERISTICS	= 10 vac, 10 = 20 Aac	9 _{fe}		12		IVITIOS
Input Capacitance		C _{ies}		1859		pF
Output Capacitance	$(V_{CE} = 25 \text{ Vdc}, V_{GE} = 0 \text{ Vdc},$	C _{les}		198		P
Transfer Capacitance	f = 1.0 MHz)			30		-
·		C _{res}	-	30		
SWITCHING CHARACTERISTICS Turn-On Delay Time				91		ns
Rise Time		t _{d(on)}	_	-	_	115
		t _r		124		-
Turn–Off Delay Time	$(V_{CC} = 720 \text{ Vdc}, I_C = 25 \text{ Adc}, V_{GE} = 15 \text{ Vdc}, L = 300 \mu\text{H}$	t _{d(off)}	_	196		
Fall Time	$R_{G} = 20 \Omega$)	t _f	—	310	_	
Turn–Off Switching Loss	Energy losses include "tail"	E _{off}	_	2.44	4.69	mJ
Turn–On Switching Loss		Eon	—	3.14	5.22	
Total Switching Loss		E _{ts}	—	5.58	9.91	
Turn–On Delay Time		t _{d(on)}	—	88	_	ns
Rise Time		t _r	—	126		
Turn–Off Delay Time	$(V_{CC} = 720 \text{ Vdc}, I_{C} = 25 \text{ Adc},$	t _{d(off)}	_	236		
Fall Time	V _{GE} = 15 Vdc, L = 300 μH R _G = 20 Ω, T _J = 125°C)	t _f	—	640	_	
Turn–Off Switching Loss	Energy losses include "tail"	E _{off}	_	5.40		mJ
Turn–On Switching Loss		E _{on}	—	5.03	_	1
Total Switching Loss		E _{ts}	_	10.43		
Gate Charge		QT	_	62		nC
7	$(V_{CC} = 720 \text{ Vdc}, I_{C} = 25 \text{ Adc},$	Q ₁	_	22		
	V _{GE} = 15 Vdc)	Q ₂		25		
DIODE CHARACTERISTICS	1	.2	1	-		
Diode Forward Voltage Drop		V _{FEC}				Vdc
(I _{EC} = 12.5 Adc)		. 20	—	2.89	3.50	
(I _{EC} = 12.5 Adc, T _J = 125°C)			I —	1.75	—	1

(1) Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

(continued)

ELECTRICAL CHARACTERISTICS — continued ($T_J = 25^{\circ}C$ unless otherwise noted)

Chara	acteristic	Symbol	Min	Тур	Max	Unit
DIODE CHARACTERISTICS — conti	nued	•				
Reverse Recovery Time		t _{rr}	—	114	—	ns
	(I _F = 25 Adc, V _R = 720 Vdc, dI _F /dt = 150 A/μs)	ta	—	71	—	
		t _b	—	43	—	
Reverse Recovery Stored Charge		Q _{RR}	—	0.65	—	μC
Reverse Recovery Time	(I _F = 25 Adc, V _R = 720 Vdc, dI _F /dt = 150 A/µs, T _J = 125°C)	t _{rr}	—	226	—	ns
		t _a	—	165	—	
		t _b	—	61	—	
Reverse Recovery Stored Charge		Q _{RR}	—	1.90	_	μC
NTERNAL PACKAGE INDUCTANCE		•				
Internal Emitter Inductance (Measured from the emitter lead 0.	25" from package to emitter bond pad)	LE	_	13	C-L	nH



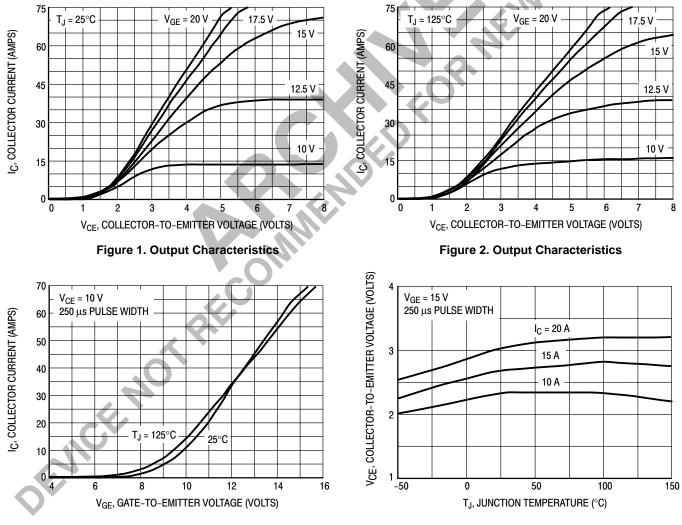
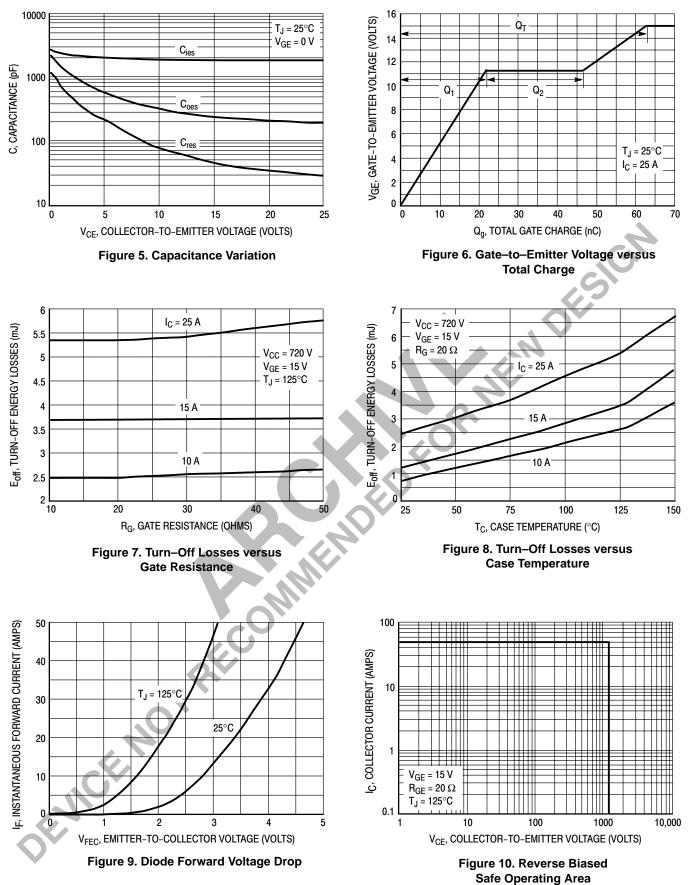
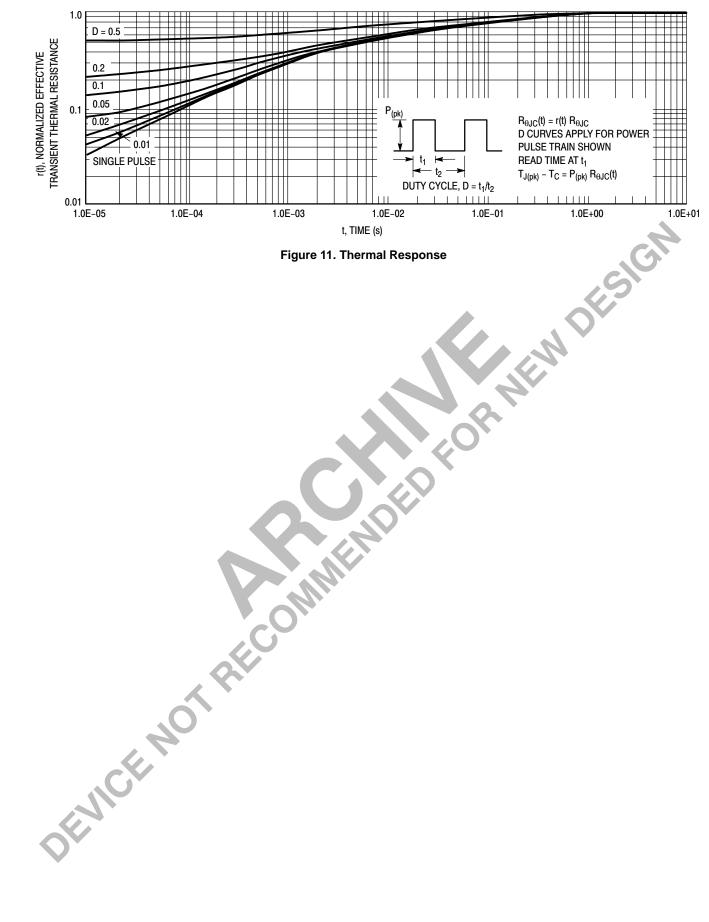


Figure 3. Transfer Characteristics

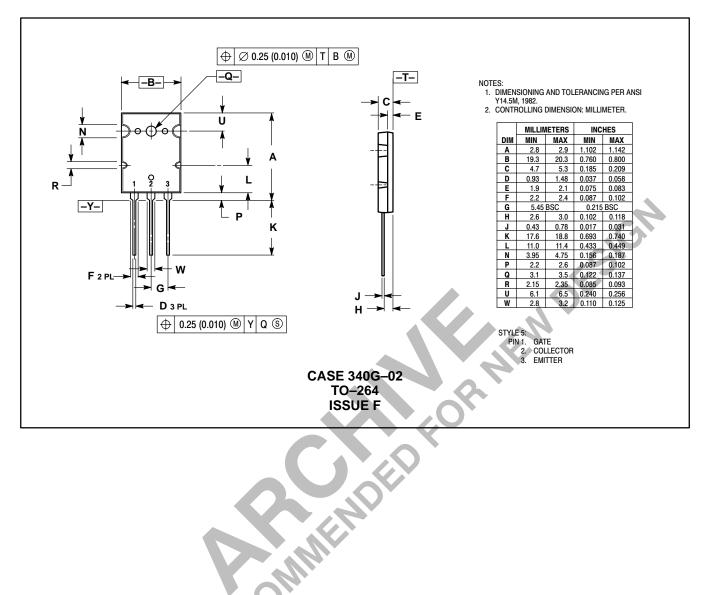
Figure 4. Collector–to–Emitter Saturation Voltage versus Junction Temperature



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PACKAGE DIMENSIONS



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